

# MA3J142E

## Silicon epitaxial planar type

For switching circuits

### ■ Features

- Small S-mini type package contained two elements, allowing high-density mounting
- Short reverse recovery time  $t_{rr}$
- Small terminal capacitance,  $C_t$

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter		Symbol	Rating	Unit
Reverse voltage (DC)		$V_R$	80	V
Peak reverse voltage		$V_{RM}$	80	V
Forward current (DC)	Single	$I_F$	100	mA
	Double		150	
Peak forward current	Single	$I_{FM}$	225	mA
	Double		340	
Non-repetitive peak forward surge current*	Single	$I_{FSM}$	500	mA
	Double		750	
Junction temperature		$T_j$	150	$^\circ\text{C}$
Storage temperature		$T_{stg}$	-55 to +150	$^\circ\text{C}$

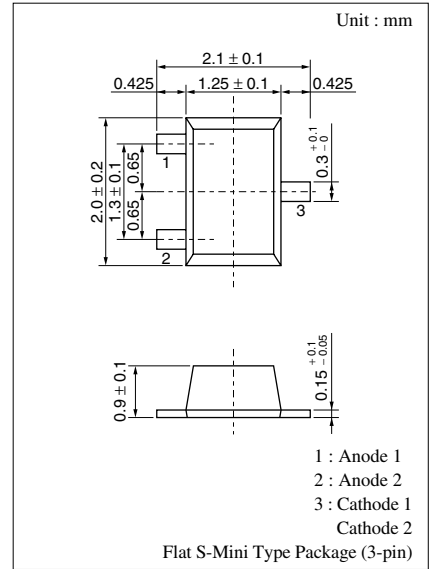
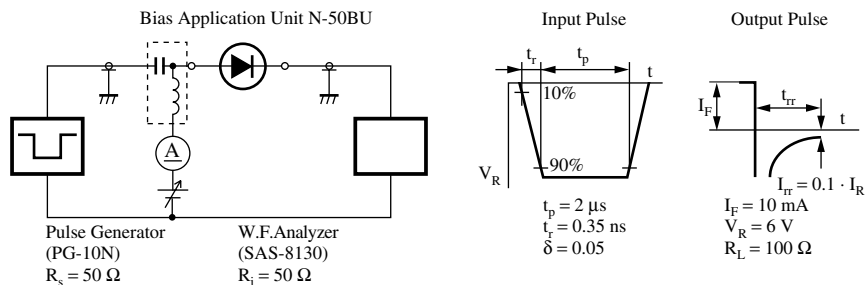
Note) \* :  $t = 1 \text{ s}$

### ■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse current (DC)	$I_R$	$V_R = 75 \text{ V}$			100	nA
Forward voltage (DC)	$V_F$	$I_F = 100 \text{ mA}$			1.2	V
Reverse voltage (DC)	$V_R$	$I_R = 100 \mu\text{A}$	80			V
Terminal capacitance	$C_t$	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$			2	pF
Reverse recovery time*	$t_{rr}$	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}$ $I_{rr} = 0.1 \cdot I_R, R_L = 100 \Omega$			3	ns

Note) 1. Rated input/output frequency: 100 MHz

2. \* :  $t_{rr}$  measuring circuit



Marking Symbol: MU

Internal Connection

